

MAXIMUM RATINGS

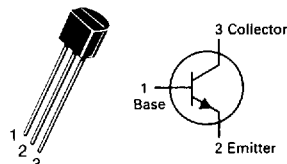
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	30	Vdc
Collector-Base Voltage	V_{CBO}	40	Vdc
Emitter-Base Voltage	V_{EBO}	4.0	Vdc
Collector Current — Continuous	I_C	50	mA dc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +135	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W

MPSH24

CASE 29-04, STYLE 2
TO-92 (TO-226AA)



VHF TRANSISTOR

NPN SILICON

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 1.0\text{ mA dc}, I_E = 0$)	$V_{(BR)CEO}$	30	—	—	Vdc
Collector-Base Breakdown Voltage ($I_C = 100\text{ }\mu\text{A dc}, I_E = 0$)	$V_{(BR)CBO}$	40	—	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10\text{ }\mu\text{A dc}, I_C = 0$)	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector Cutoff Current ($V_{CB} = 15\text{ Vdc}, I_E = 0$)	I_{CBO}	—	—	50	nA dc

ON CHARACTERISTICS

DC Current Gain ($I_C = 8.0\text{ mA dc}, V_{CE} = 10\text{ Vdc}$)	h_{FE}	30	—	—	—
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SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ($I_C = 8.0\text{ mA dc}, V_{CE} = 10\text{ Vdc}, f = 100\text{ MHz}$)	f_T	400	620	—	MHz
Collector-Base Capacitance ($V_{CB} = 10\text{ Vdc}, I_E = 0, f = 1.0\text{ MHz}$)	C_{cb}	—	0.25	0.36	pF
Conversion Gain (213 MHz to 45 MHz) ($I_C = 8.0\text{ mA dc}, V_{CC} = 20\text{ Vdc}$, Oscillator Injection = 150 mVrms) (60 MHz to 45 MHz) ($I_C = 8.0\text{ mA dc}, V_{CC} = 20\text{ Vdc}$, Oscillator Injection = 150 mVrms)	G_C	19 24	24 29	—	dB

6367254 0103679 742

CONVERSION GAIN CHARACTERISTICS

(TEST CIRCUIT FIGURE 7)

 $(V_{CC} = 20 \text{ Vdc}, R_S = R_L = 50 \text{ Ohms}, f_{if} = 44 \text{ MHz}, \text{B.W.} = 6.0 \text{ MHz})$

FIGURE 1 – CONVERSION GAIN versus COLLECTOR CURRENT

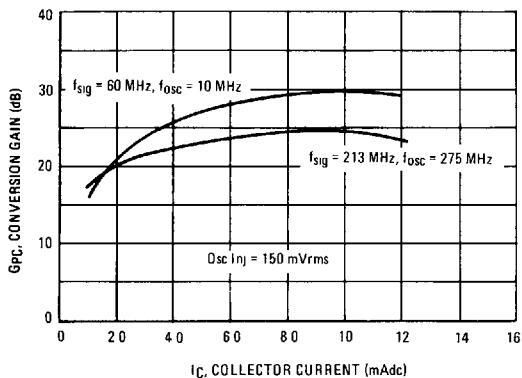


FIGURE 2 – CONVERSION GAIN versus INJECTION LEVEL

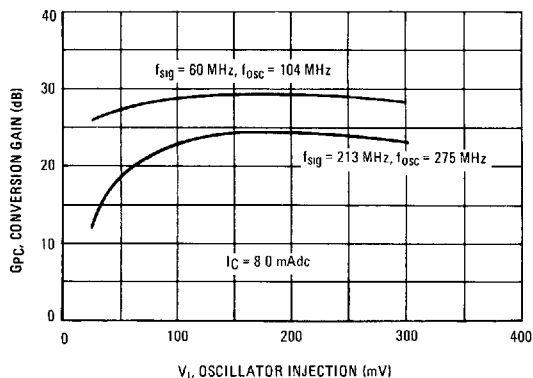
COMMON-EMITTER y PARAMETERS $(V_{CE} = 15 \text{ Vdc}, T_A = 25^\circ\text{C})$

FIGURE 3 – INPUT ADMITTANCE

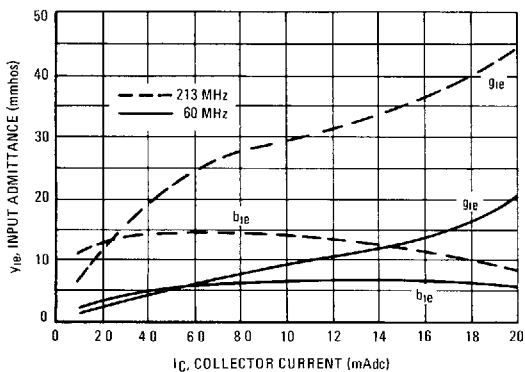


FIGURE 4 – REVERSE TRANSFER ADMITTANCE

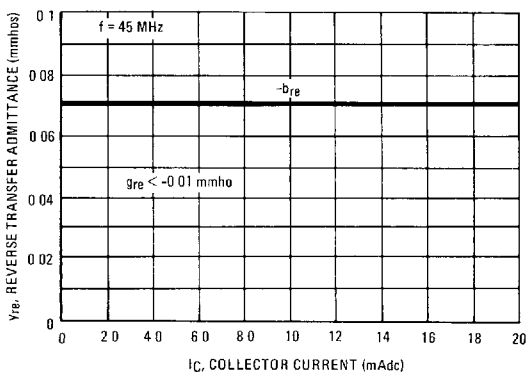


FIGURE 5 – FORWARD TRANSFER ADMITTANCE

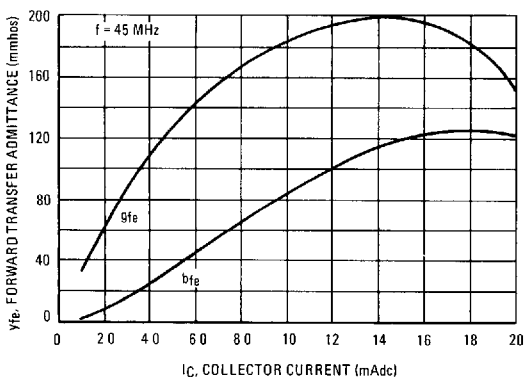


FIGURE 6 – OUTPUT ADMITTANCE

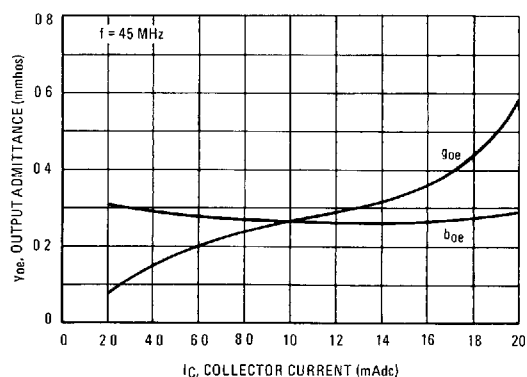


FIGURE 7 – VHF MIXER TEST CIRCUIT

 $(f_{if} = 44 \text{ MHz}, \text{B.W.} = 6.0 \text{ MHz})$ 